

PAM3103

300mA ADJUSTABLE HIGH PSRR CMOS LINEAR REGULATOR

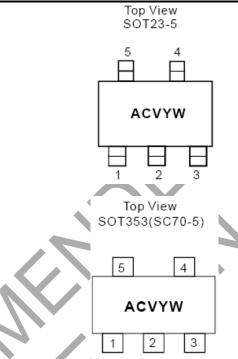
Description

The PAM3103 is a positive, adjustable linear regulator. It features low quiescent current ($65\mu A$ typ.) and low dropout voltage, making it ideal for battery powered applications. The output voltage is adjustable from 1.2V through 5V. Its high PSRR makes it useful in applications that require AC noise suppression on the input power supply. Space-saving SOT23-5 and SOT353(SC70-5) packages are attractive for portable and handheld applications. It has both thermal shutdown and a current limit features to prevent device failure under extreme operating conditions. It is stable with an output capacitor of 2.2 μ F or greater.

Features

- Low Dropout Voltage: 180mV@ 300mA (V_O = 3.3V)
- Accuracy within ±2%
- Quiescent Current: 65μA Typ.
- High PSRR: 67dB@100Hz
- Excellent Line/Load Regulation
- Fast Response
- Current Limiting
- Short Circuit Protection
- Low Temperature Coefficient
- Shutdown Current: 0.5µA
- Thermal Shutdown
- Space Saving Packages SOT23-5 and SOT353(SC70-5)
- Pb-Free Package

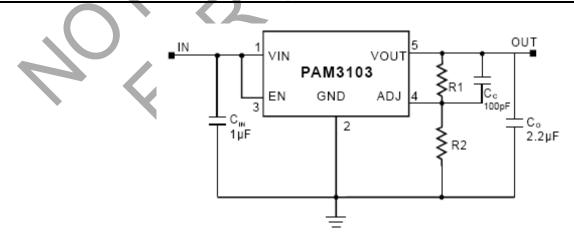
Pin Assignments



Applications

- Cordless Phone
- Cellular Phone
- Bluetooth Earphone
 - Digital Camera
- Portable Electronics
- WLAN
- MP3 Player

Typical Applications Circuit



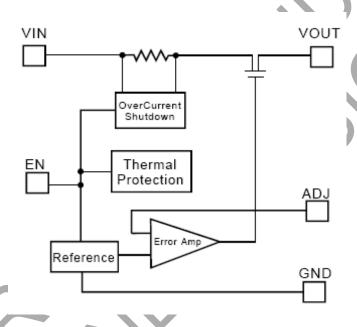
 $V_O = V_{REF}^*(R1+R2)/R2$



Pin Descriptions

| Pin Number | Pin Name | Function |
|---------------|-------------|---------------------------|
| 1 | VIN | Input |
| 2 | GND | Ground |
| 3 | EN | Chip Enable (Active High) |
| 4 | ADJ | Adjustable Pin |
| 5 | VOUT | Output |

Functional Block Diagram



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

These are stress ratings only and functional operation is not implied. Exposure to absolute maximum ratings for prolonged time periods may affect device reliability. All voltages are with respect to ground.

| Parameter | Rating | Unit |
|----------------------------|-----------------------------------|------|
| Inout Voltage | 6.0 | V |
| Output Current | 300 | mA |
| Output Pin Voltage | GND -0.3 to V _{IN} +0.3V | V |
| Lead Soldering Temperature | 300 | °C |
| Storage Temperature | -65 to +150 | °C |



Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

| Parameter | Rating | Unit |
|-----------------------|-------------|------|
| Supply Voltage Range | 2.5 to 5.5 | V |
| Junction Temperature | -40 to +125 | °C |
| Operation Temperature | -40 to +85 | |

Thermal Information

| Parameter | Symbol | Package | Max | Unit |
|--|-----------------|----------------|-----|-------|
| Thermal Desigtance Junction to Cook | 0 | SOT23-5 | 130 | Y |
| Thermal Resistance Junction to Case) | θ _{JC} | SOT353(SC70-5) | TBD | °C/W |
| Thermal Decistores (Innation to Ambient) | θја | SOT23-5 | 250 | C/VV |
| Thermal Resistance (Junction to Ambient) | | SOT353(SC70-5) | 300 | |
| Internal Power Dissipation | D | SOT23-5 | 400 | mW |
| Internal Fower Dissipation | P_{D} | SOT353(SC70-5) | 300 | TIIVV |

Electrical Characteristics (@T_A = +25°C, V_{IN} = 4V, V_O = 3V, C_{IN} = 1 μ F, C_O = 2.2 μ F, unless otherwise specified.)

| Parameter | Symbol | Test Cond | litions | Min | Тур | Max | Units |
|-------------------------------|--|---|-----------------------|--------|-------|--------|---------------|
| Input Voltage | V _{IN} | - 1 | | Note 1 | _ | 5.5 | V |
| Output Voltage | Vo | | | 1.2 | _ | 5 | V |
| Reference Voltage | V _{REF} | † ^ | | _ | 1.235 | _ | V |
| Output Voltage Accuracy | Vo | $I_{O} = 1mA$ | | -2 | _ | 2 | % |
| Output Current | lo | - | | 300 | _ | Note 2 | mA |
| Short Circuit Current | Isc | V _O = 0V | | _ | 150 | _ | mA |
| Dropout Voltage | V | | $2.5V \le V_O < 3.3V$ | _ | 370 | 450 | - mV |
| Dropout Voltage | VDROP | $I_0 = 300 \text{mA}$ | V _O ≥ 3.3V | _ | 180 | 230 | |
| Ground Current | I _{GND} | $I_O = 1$ mA to 300mA | | _ | 70 | 90 | μA |
| Quiescent Current | lq | $I_O = 0mA$ | | _ | 65 | 90 | μΑ |
| Line Regulation | LNR | $I_0 = 1 \text{mA}, V_{IN} = 3 \text{V to 5}$ | V | -0.4 | 0.2 | 0.4 | %/V |
| Load Regulation | LDR | I _O = 1mA to 300mA | | -1 | 0.2 | 1 | % |
| Temperature Coefficient | Tc | _ | | _ | 40 | _ | ppm/°C |
| Over Temperature Shutdown | OTS | I _O = 1mA | | _ | 150 | _ | °C |
| Over Temperature Hysteresis | OTH | I _O = 1mA | | _ | 30 | _ | °C |
| | | | f = 100Hz | _ | 67 | _ | dB |
| Power Supply Ripple Rejection | PSRR | $I_O = 100$ mA, $V_O = 1.2$ V | f = 1kHz | _ | 65 | 1 | dB |
| | | | f = 10kHz | _ | 42 | _ | dB |
| Output Noise | V_N | f = 10Hz to 100kHz | | | 50 | _ | μV_{RMS} |
| EN Input High Threshold | V _{IH} | V _{IN} 2.5V to 5V | | 1.5 | _ | _ | V |
| EN Input Low Threshold | V_{IL} | V _{IN} 2.5V to 5V | | _ | _ | 0.3 | V |
| Shutdown Current | own Current I _{SD} V _{EN} = 0V | | _ | 0.01 | 1 | μA | |

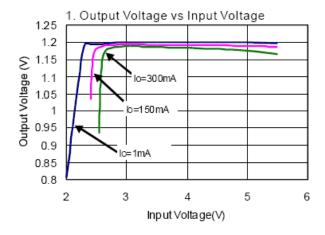
Notes: 1. The minimum input voltage (V_{IN(MIN)}) of the PAM3103 is determined by output voltage and dropout voltage. The minimum input voltage is defined as: V_{IN(MIN)} = V_O +V_{DROP}

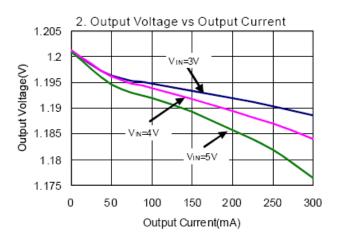
 $V_{IN(MIN)} = 2.5V$

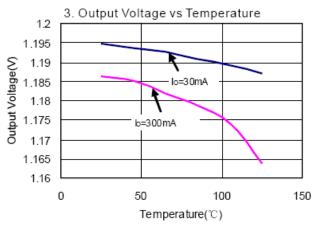
^{2.} Output current is limited by P_D , maximum $I_O = P_D/(V_{IN(MAX)} - V_O)$.

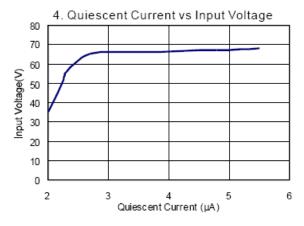


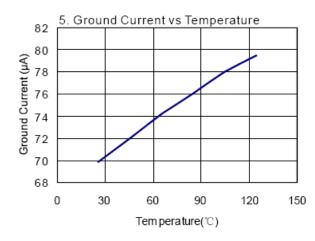
$\textbf{Typical Performance Characteristics} \ (@T_A = +25^{\circ}C,\ V_O = 1.2V,\ C_{IN} = 1\mu\text{F},\ C_O = 2.2\mu\text{F},\ unless otherwise specified.})$

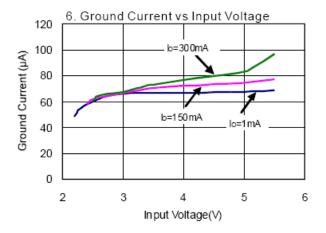






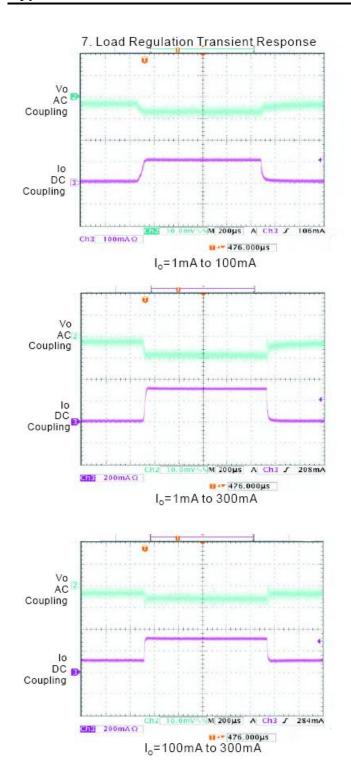


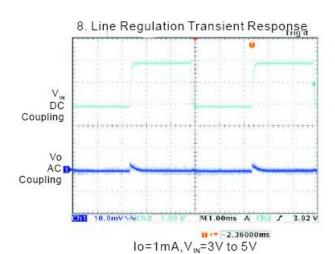


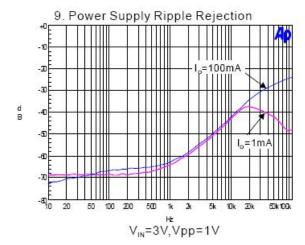




Typical Performance Characteristics (cont.)









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PAM3103

Application Information

Capacitor Selection and Regulator Stability

Similar to any low dropout regulator, the external capacitors used with the PAM3103 must be carefully selected for regulator stability and performance.

A capacitor C_{IN} of more than $1\mu F$ can be employed in the input pin, while there is no upper limit for the capacitance of C_{IN} . Please note that the distance between C_{IN} and the input pin of the PAM3103 should not exceed 0.5 inch. Ceramic capacitors are suitable for the PAM3103. Capacitors with larger values and lower ESR (equivalent series resistance) provide better PSRR and line-transient response.

The PAM3103 is designed specifically to work with low ESR ceramic output capacitors in order to save space and improve performance. Using an output ceramic capacitor whose value is > 2.2μ F with ESR>5m Ω ensures stabilty.

ADJ Output Voltage Programming

The output voltage of the PAM3103 adjustable regulator is programed by using an external resistor divider as shown in Figure 1. The output voltage is calculated as below:

$$V_O = V_{REF}(1 + R1/R2)$$

Resistor R1 and R2 should be chosen for approximately 7μ A divider current. Lower value resistors can be used but offer no advantage and waste more power. Higher value should be avoided as leakage current at ADJ pin increase the output voltage error. CC is unnecessary when R1 or R2 <20k Ω . The recommended design procedure is to choose R2 =169k Ω to set the divider current at 7μ A and then calculate R1 as below:

$$R1 = (V_O/V_{REF} - 1)R2$$

Load Transient Considerations

Curve 7 of the PAM3103 load-transient response on page 5 shows two components of the output response: a DC shift from the output impedance due to the load current change and transient response. The DC shift is quite small due to excellent load regulation of the PAM3103. The transient spike, resulting from a step change in the load current from 1mA to 300mA, is 20mV. The ESR of the output capacitor is critical to the transient spike. A larger capacitance along with smaller ESR results in a smaller spike.

Shutdown Input Operation

The PAM3103 can be shut down by pulling the EN input low, and turned on by tying the EN input to V_{IN} or leaving the EN input floating.

Internal P-Channel Pass Transistor

The PAM3103 features a 0.75Ω device as a pass transistor. The PMOS pass transistor enables the PAM3103 to consume only 65μ A of ground current during low dropout, light-load, or heavy-load operation. This feature increases the battery operation life time.

Input-Output (Dropout) Voltage

A regulator's minimum input-output voltage differential (or dropout voltage) determines the lowest usable supply voltage. The PAM3103 has a typical 300mV dropout voltage. In battery powered systems, this will determine the useful end-of-life battery voltage.

Current Limit and Short Circuit Protection

The PAM3103 features a current limit, which monitors and controls the gate voltage of the pass transistor. The output current can be limited to 400mA by regulating the gate voltage. The PAM3103 also has a built-in short circuit current limit.



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PAM3103

Application Information (cont.)

Thermal Considerations

Thermal protection limits power dissipation in the PAM3103. When the junction temperature exceeds +150°C, the OTP (Over Temperature Protection) starts the thermal shutdown and turns the pass transistor off. The pass transistor resumes operation after the junction temperature drops below +120°C.

For continuous operation, the junction temperature should be maintained below +125°C. The power dissipation is defined as below:

$$P_D = (V_{IN} - V_{OUT})^* I_O + V_{IN}^* I_{GND}$$

The maximum power dissipation depends on the thermal resistance of IC package, PCB layout, the rate of surrounding airflow and temperature difference between junction and ambient. The maximum power dissipation can be calculated by the following formula:

$$P_{D(MAX)} = (T_{J(MAX)} - T_A)/\theta_{JA}$$

Where $T_{J(MAX)}$ is the maximum allowable junction temperature +125°C, T_A is the ambient temperature and θ_{JA} is the thermal resistance from the junction to the ambient.

For example, as θ_{JA} is 250°C/W for the SOT-23 package based on the standard JEDEC 51-3 for a single-layer thermal test board, the maximum power dissipation at $T_A = +25$ °C can be calculated by following formula:

$$P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C)/250 = 0.4W$$

It is also useful to calculate the junction temperature of the PAM3103 under a set of specific conditions. Suppose the input voltage $V_{IN} = 3.3V$, the output current $I_O = 300$ mA and the case temperature $T_A = +40$ °C measured by a thermal couple during operation, the power dissipation is defined as:

$$P_D = (3.3V - 2.8V) * 300mA + 3.3V * 70\mu A \cong 150mW$$

And the junction temperature T_J can be calculated as follows:

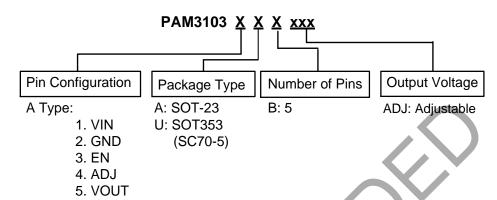
$$T_J = TA + PD^* \theta_{JA}$$

 $T_J = 40^{\circ}C + 0.15W^*250^{\circ}C/W$
 $= 40^{\circ}C + 37.5^{\circ}C$
 $= 77.5^{\circ}C < T_{J(MAX)} = +125^{\circ}C_{J}$

For this application, T_J is lower than the absolute maximum operating junction temperature +125°C, so it is safe to use the PAM3103 in this configuration.

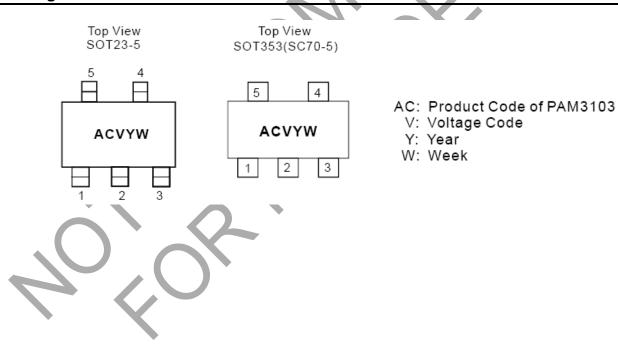


Ordering Information



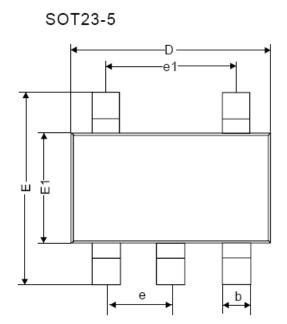
| Part Number | Output Voltage | Part Marking | Package Type | Standard Package |
|---------------|----------------|--------------|----------------|---------------------|
| PAM3103AABADJ | ADJ | ACAYW | SOT23-5 | 3000Units/Tape&Reel |
| PAM3103AUBADJ | ADJ | ACAYW | SOT353(SC70-5) | 3000Units/Tape&Reel |

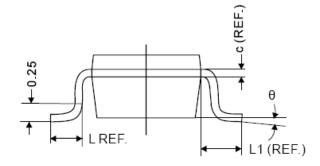
Marking Information

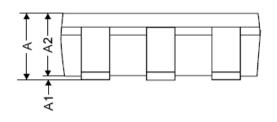




Package Outline Dimensions (All dimensions in mm.)







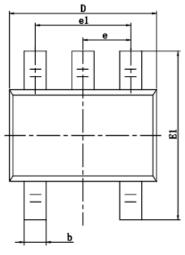
| DEE | Millimeter | | |
|------|------------|------|--|
| REF. | Min | Max | |
| Α | 1.10 MAX | | |
| A1 | 0 | 0.10 | |
| A2 | 0.70 | 1 | |
| O | 0.12 F | REF. | |
| О | 2.70 | 3.10 | |
| Е | 2.60 | 3.00 | |
| E1 | 1.40 | 1.80 | |
| L | 0.45 F | REF. | |
| L1 | 0.60 REF. | | |
| θ | 0° | 10° | |
| b | 0.30 | 0.50 | |
| е | 0.95 REF. | | |
| e1 | 1.90 REF. | | |

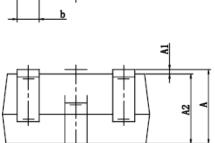


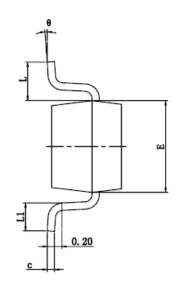


Package Outline Dimensions (cont.) (All dimensions in mm.)

SOT353(SC70-5)







| Symbol | Dimensions In Millimeters | | Dimensions In Inches | | |
|--------|---------------------------|-------|----------------------|-------|--|
| Symbol | Min | Max | Min | Max | |
| Α | 0.900 | 1.100 | 0.035 | 0.043 | |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 | |
| A2 | 0.900 | 1.000 | 0.035 | 0.039 | |
| b | 0.150 | 0.350 | 0.006 | 0.014 | |
| С | 0.080 | 0.150 | 0.003 | 0.006 | |
| D | 2.000 | 2.200 | 0.079 | 0.087 | |
| E | 1.150 | 1.350 | 0.045 | 0.053 | |
| E1 | 2.150 | 2.450 | 0.085 | 0.096 | |
| е | 0.650 TYP | | 0.026 TYP | | |
| e1 | 1.200 | 1.400 | 0.047 | 0.055 | |
| L | 0.525 REF | | 0.021 REF | | |
| L1 | 0.260 | 0.460 | 0.010 | 0.018 | |
| θ | 0 | 8 | 0 | 8 | |





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PAM3103

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